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FEATURES

- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- Lower Leakage Current : 10 μ A (Max.) @ $V_{DS} = 100V$
- Lower $R_{DS(ON)}$: 0.176 Ω (Typ.)

$$BV_{DSS} = 100 \text{ V}$$

$$R_{DS(on)} = 0.22 \text{ } \Omega$$

$$I_D = 2.3 \text{ A}$$

SOT-223



1. Gate 2. Drain 3. Source

Absolute Maximum Ratings

Symbol	Characteristic	Value	Units
V_{DSS}	Drain-to-Source Voltage	100	V
I_D	Continuous Drain Current ($T_C=25^\circ\text{C}$)	2.3	A
	Continuous Drain Current ($T_C=70^\circ\text{C}$)	1.85	
I_{DM}	Drain Current-Pulsed (1)	18	A
V_{GS}	Gate-to-Source Voltage	± 20	V
E_{AS}	Single Pulsed Avalanche Energy (2)	105	mJ
I_{AR}	Avalanche Current (1)	2.3	A
E_{AR}	Repetitive Avalanche Energy (1)	0.27	mJ
dv/dt	Peak Diode Recovery dv/dt (3)	6.5	V/ns
P_D	Total Power Dissipation ($T_C=25^\circ\text{C}$) *	2.7	W
	Linear Derating Factor *	0.022	W/ $^\circ\text{C}$
T_J, T_{STG}	Operating Junction and Storage Temperature Range	- 55 to +150	$^\circ\text{C}$
T_L	Maximum Lead Temp. for Soldering Purposes, 1/8" from case for 5-seconds	300	

Thermal Resistance

Symbol	Characteristic	Typ.	Max.	Units
$R_{\theta JA}$	Junction-to-Ambient *	--	46.3	$^\circ\text{C/W}$

* When mounted on the minimum pad size recommended (PCB Mount).

Electrical Characteristics ($T_C=25\text{ }^\circ\text{C}$ unless otherwise specified)

Symbol	Characteristic	Min.	Typ.	Max.	Units	Test Condition
BV_{DSS}	Drain-Source Breakdown Voltage	100	--	--	V	$V_{GS}=0V, I_D=250\mu A$
$\Delta BV/\Delta T_J$	Breakdown Voltage Temp. Coeff.	--	0.09	--	V/ $^\circ\text{C}$	$I_D=250\mu A$ See Fig 7
$V_{GS(th)}$	Gate Threshold Voltage	1.0	--	2.0	V	$V_{DS}=5V, I_D=250\mu A$
I_{GSS}	Gate-Source Leakage , Forward	--	--	100	nA	$V_{GS}=20V$
	Gate-Source Leakage , Reverse	--	--	-100		$V_{GS}=-20V$
I_{DSS}	Drain-to-Source Leakage Current	--	--	10	μA	$V_{DS}=100V$
		--	--	100		$V_{DS}=80V, T_C=125\text{ }^\circ\text{C}$
$R_{DS(on)}$	Static Drain-Source On-State Resistance	--	--	0.22	Ω	$V_{GS}=5V, I_D=1.15A$ (4)
g_{fs}	Forward Transconductance	--	4.6	--	\bar{O}	$V_{DS}=40V, I_D=1.15A$ (4)
C_{iss}	Input Capacitance	--	340	440	pF	$V_{GS}=0V, V_{DS}=25V, f=1\text{MHz}$ See Fig 5
C_{oss}	Output Capacitance	--	90	115		
C_{rss}	Reverse Transfer Capacitance	--	39	50		
$t_{d(on)}$	Turn-On Delay Time	--	5	20	ns	$V_{DD}=50V, I_D=9.2A,$ $R_G=9\ \Omega$ See Fig 13 (4)(5)
t_r	Rise Time	--	10	30		
$t_{d(off)}$	Turn-Off Delay Time	--	19	50		
t_f	Fall Time	--	9	30		
Q_g	Total Gate Charge	--	10.2	15	nC	$V_{DS}=80V, V_{GS}=5V,$ $I_D=9.2A$ See Fig 6 & Fig 12 (4)(5)
Q_{gs}	Gate-Source Charge	--	1.7	--		
Q_{gd}	Gate-Drain ("Miller") Charge	--	6.0	--		

Source-Drain Diode Ratings and Characteristics

Symbol	Characteristic	Min.	Typ.	Max.	Units	Test Condition
I_S	Continuous Source Current	--	--	2.3	A	Integral reverse pn-diode in the MOSFET
I_{SM}	Pulsed-Source Current (1)	--	--	18		
V_{SD}	Diode Forward Voltage (4)	--	--	1.5	V	$T_J=25\text{ }^\circ\text{C}, I_S=2.3A, V_{GS}=0V$
t_{rr}	Reverse Recovery Time	--	98	--	ns	$T_J=25\text{ }^\circ\text{C}, I_F=9.2A$
Q_{rr}	Reverse Recovery Charge	--	0.34	--	μC	$di_F/dt=100A/\mu\text{s}$ (4)

Notes ;

- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- ② $L=30\text{mH}, I_{AS}=2.3A, V_{DD}=25V, R_G=27\Omega,$ Starting $T_J=25\text{ }^\circ\text{C}$
- ③ $I_{SD} \leq 9.2A, di/dt \leq 300A/\mu\text{s}, V_{DD} \leq BV_{DSS},$ Starting $T_J=25\text{ }^\circ\text{C}$
- ④ Pulse Test : Pulse Width = $250\mu\text{s},$ Duty Cycle $\leq 2\%$
- ⑤ Essentially Independent of Operating Temperature

Fig 1. Output Characteristics

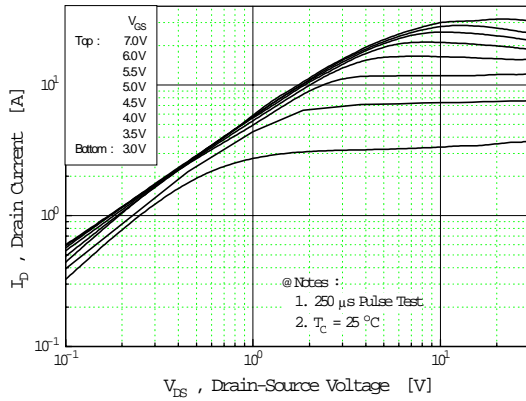


Fig 2. Transfer Characteristics

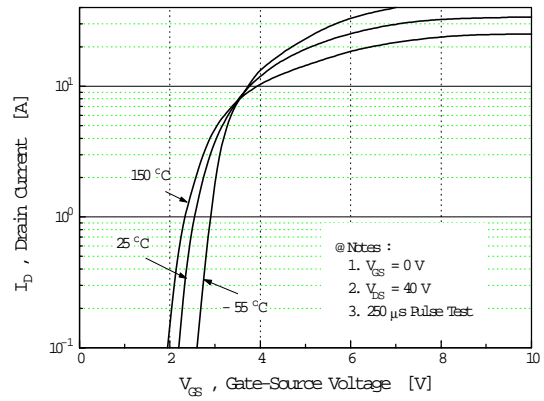


Fig 3. On-Resistance vs. Drain Current

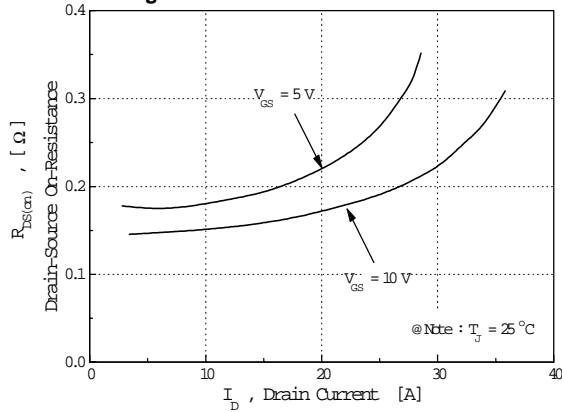


Fig 4. Source-Drain Diode Forward Voltage

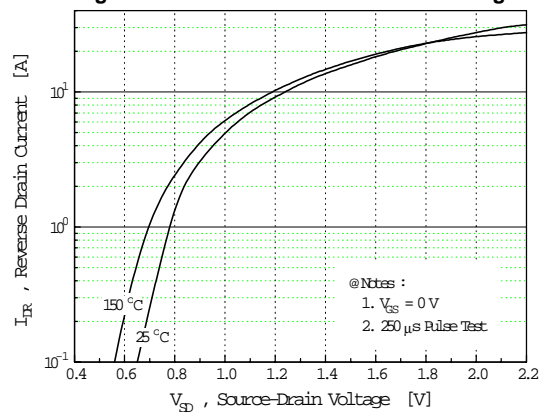


Fig 5. Capacitance vs. Drain-Source Voltage

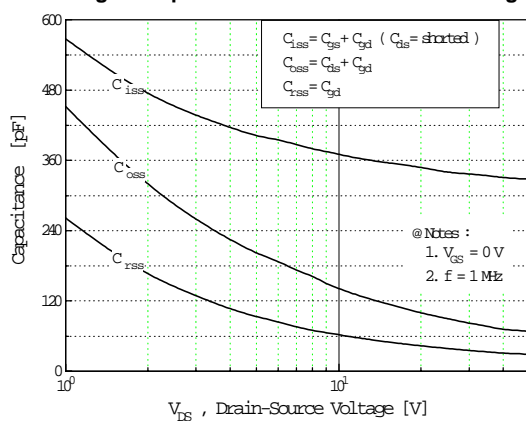


Fig 6. Gate Charge vs. Gate-Source Voltage

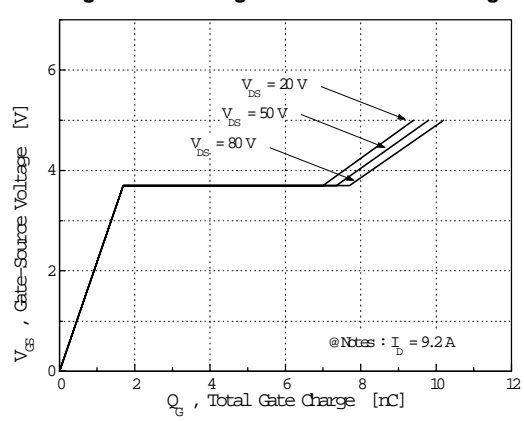


Fig 7. Breakdown Voltage vs. Temperature

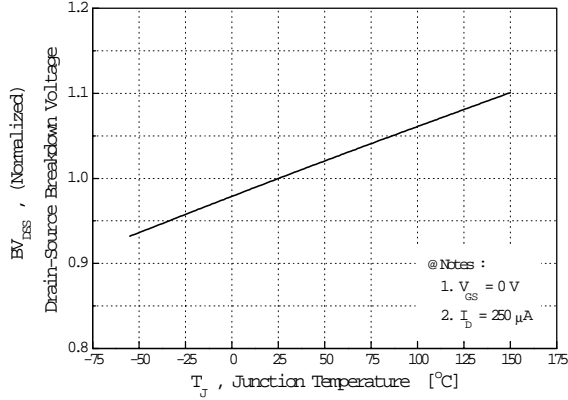


Fig 8. On-Resistance vs. Temperature

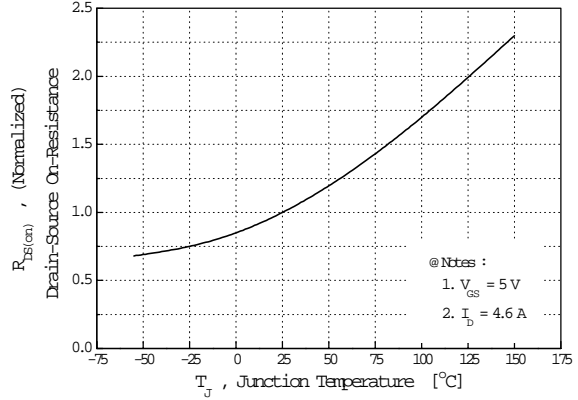


Fig 9. Max. Safe Operating Area

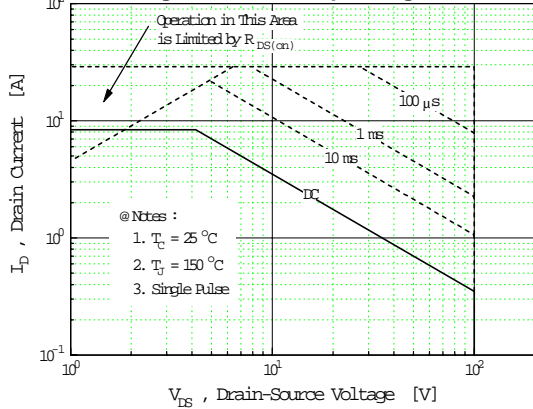


Fig 10. Max. Drain Current vs. Case Temperature

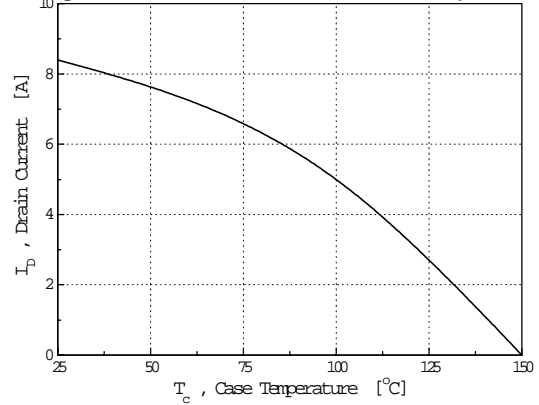


Fig 11. Thermal Response

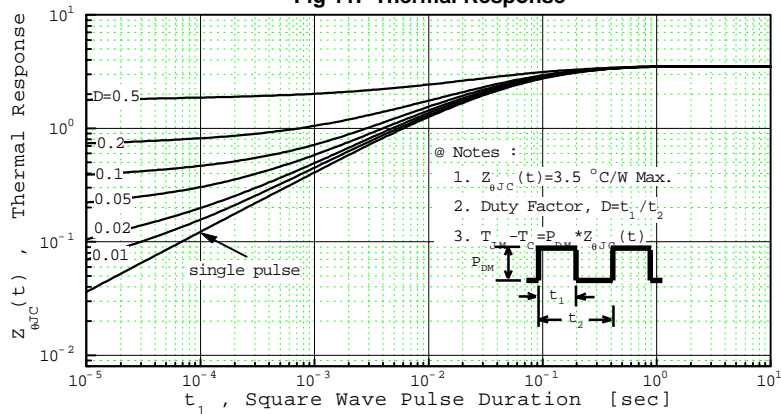


Fig 12. Gate Charge Test Circuit & Waveform

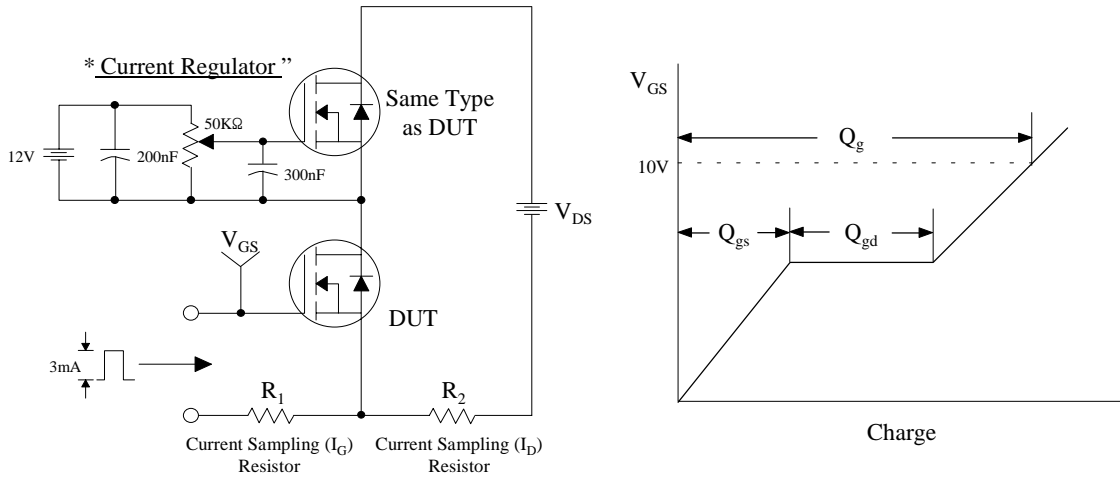


Fig 13. Resistive Switching Test Circuit & Waveforms

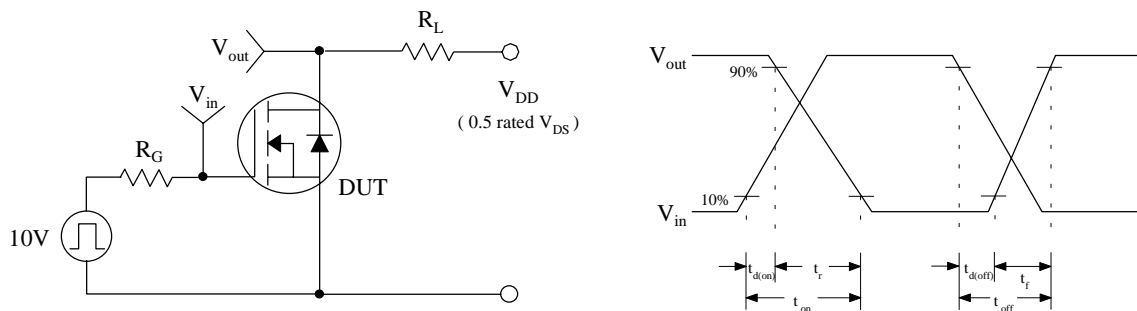


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

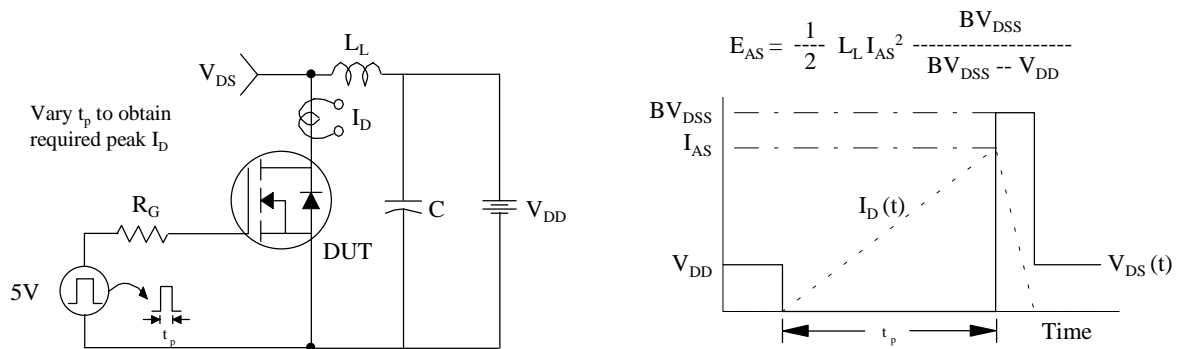
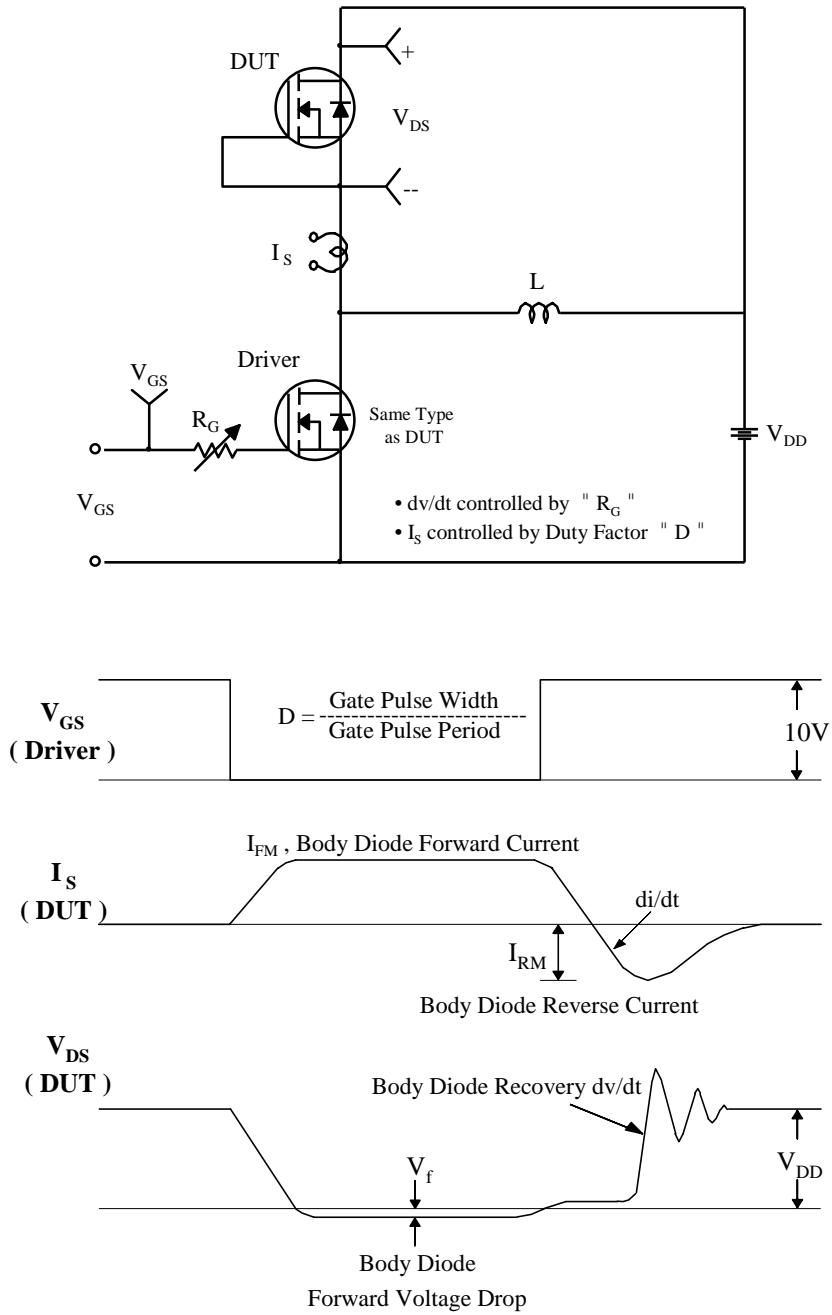


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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